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Strongly Correlated Electronic Materials

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Abstract

This is the final report of a three-year, Laboratory-Directed Research and Development (LDRD) project at the Los Alamos National Laboratory (LANL). Novel electronic materials characterized by strong electronic correlations display a number of unexpected, often extraordinary, properties. These are likely to play a major role in purpose-specific high-technology electronic materials of the future developed for electronic, magnetic and optical applications. This project sought to develop predictive control of the novel properties by formulating, solving and applying many-body models for the underlying microscopic physics. This predictive control required the development of new analytical and numerical many-body techniques and strategies for materials of varying strengths of interactions, dimensionality and geometry. The results of these techniques are then compared with experimental data on classes of novel materials, and the robust techniques are used to predict additional properties and motivate key additional experiments.

1. Background and Research Objectives

The last fifteen years has been a golden age for electronic materials with startling new discoveries of classes of phenomena and of complex electronic materials exhibiting them – heavy fermions, electronic polymers, spin glasses, high-temperature superconductors (HTS), nanoscale materials, fullerenes, fractional quantum Hall materials, giant magneto-resistance materials, etc. These and related electronic materials are distinguished by a radical paradigm shift in solid state and materials science: away from traditional isotropic three-dimensional materials with simple unit cells, near-perfect crystal order, and linear, equilibrium responses; to anisotropic structures (clusters, chains and layers) with local, multiscale intrinsic and extrinsic

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disorder (texture) playing functional roles, and delicate balances of strong coupling between spin-charge-lattice degrees-of-freedom leading to a huge variety of broken-symmetry ground states (ferroelectric, martensitic, charge-density, spin-density, superconducting) driving strongly nonlinear and nonequilibrium excitations and responses. These novel electronic and structural states of matter and materials classes are, in the last few years, taking the first steps from academia to technology, since they offer the tunability (electronic, magnetic, optical) and breadth of characteristics demanded by high-technology requirements for next-generation "new materials." The need for control of advanced electronic materials now makes this theory and modeling guidance imperative for both fundamental understanding and technological competencies.

This project provided theory support for experimental activities in high-temperature superconductors, heavy-fermion materials with an emphasis on the Kondo insulators, and perovskite materials including the colossal magnetoresistance materials (CMR). In addition to these material-specific activities, we also addressed a number of issues that are common themes in these broad classes of materials. This included the study of these materials in magnetic fields, exploring properties like the field-induced metal-insulator transition, colossal magnetoresistance, spin-gap phenomena in HTS, the quantum Hall effect (QHE), and related issues. The properties of unconventional superconductors and impurity bound states in them were also studied. Another important theme is the metal-insulator transition and the nature of the metallic state in low-dimensional strongly correlated electronic materials.

2. Importance to LANL's Science and Technology Base and National R&D Needs

Over the last ten years, Los Alamos has taken advantage of its interdisciplinary skills to establish a uniquely powerful presence in this arena of novel electronic materials. This excellence in fundamental research and interdisciplinary team-building now places LANL at the very forefront of technology innovation in electronic materials. The science developed on this project is at the forefront of new applications research. At the same time the materials studied present us with some of the most fundamental challenges in many-body theory. They include the colossal magneto-resistive materials that will have an enormous impact on the recording industry, heavy-fermions and, in particular, the Kondo insulators to be used for thermo-electric coolers, and the high temperature superconductors that are now on the brink of major applications with the recent breakthrough in HTS tape design. The impact of this project will be both on fundamental issues in correlated electron theory as well as on the characterization and design of new and novel electronic devices. This project supports Los Alamos core

competencies in nuclear and advanced materials as well as theory, modeling and high-performance computing.

3. Scientific Approach and Results to Date

This project brought together a broad range of advanced many-body techniques to study key classes of strongly correlated electronic materials. The variety of physical phenomena exhibited necessitated a multi-technique approach. The exhibited techniques are complementary to one another and provide input and testing grounds for the various approaches. These include a number of analytic methods, field theoretic methods, bosonization, parquet, and weak coupling perturbation theory as well as variational techniques and mean field theories, $1/N$, inhomogeneous and unrestricted Hartree-Fock. There are also a variety of numerical methods, LDA, exact diagonalization, QMC, and MaxEnt. These techniques were applied to a broad spectrum of intellectually challenging and technologically important materials.

- We developed a microscopic understanding of the M-I transition. We studied the field induced M-I transition and its relation to CMR materials and the heavy-fermion insulators.
- We studied the optical properties of insulators and the dynamic correlation functions. Sum rules were used to study bounds on excitons in the heavy-fermion insulators as well as in semiconducting materials.
- In the metallic phase we studied extensions of the local Fermi liquid theory to include strong antiferromagnetic correlations. We explored the field induced metal-insulator transition in this model.
- We used numerical and analytical techniques to understand multi-band, Peierls-Hubbard model Hamiltonians. Here the multi-band nature is critical to capturing essential hybridization effects, and the coupling of electronic and lattice degrees-of-freedom.
- We studied doping states with respect to the stoichiometric ground states. Relevant polaron issues that we can now address include: ordering of polarons into superlattices and their melting as a function of temperature, quantum fluctuations, density, polaron size, and lattice commensurability.
- In the case of CMR materials recently studied at LANL (e.g., $\text{La}_{1-x}\text{Ca}_x\text{MnO}_3$) we developed a double-exchange Jahn-Teller model to study the systematic influence of temperature, magnetic field, and doping on magnetic, electronic and structural ground states, and on the structure and mobility of polarons as functions of mixed-valency.

- We have solved essentially exactly for the quantum tunneling probability of a particle in the presence of inelastic degrees of freedom to calculate the effects of many-body electron-phonon interactions on the properties of realistic resonant tunneling diodes and quantum dots.
- We used the Eliashberg equations to investigate the complicated role of disorder in the strongly-coupled superconducting state. The weak localization theory and the Anderson localization problem have been developed as methods to address the role of impurities.
- An impurity in a d-wave superconductor generates a bound state, in analogy to the mid-gap impurity states in semiconductors. We have studied how these bound states produce significant contribution to the optical conductivity and, in principle, could account for the nontrivial temperature dependence of the conductivity.
- We have calculated the phase shifts and exponents entering into the transition probability rates for the x-ray problem. We also calculated the decay rate of the electron into fractionally charged quasiparticles.
- We have begun for the first time to study systematically the ground-state properties of the Anderson lattice models. The results of this study are providing benchmarks of the fidelity of the model relative to experimental systems and of past approximations to the properties of the model.
- We have combined techniques with methods for the optimization of nuclear and phonon degrees of freedom, such as conjugate gradients, Monte Carlo and molecular dynamics. We are exploring a variety of possible real-world test cases such as the calculation of the atomic structure of amorphous and liquid silicon using semi-empirical tight-binding potentials.

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